INSTRUCTION MANUAL FTV-250

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YAESU MUSEN CO., LTD.

TOKYO JAPAN

FTV-250

TWO METER TRANSVERTER



The Model FTV-250 is an all solid-state two meter transverter designed for two meter operation in conjunction with the FT-101/277, FL-101/FR-101 or FT-201 series HF transceiver.

Advanced solid-state circuit offers unsurpassed stability and clean signals at an input of 20 watts on 144 through 148 MHz. The spurious radiations are extremely reduced or eliminated by the use of dual balanced mixer in the exciter stage.

The low noise and high gain dual-gates MOS FET provides superior receiver front end.

The entire two meter band is devided into two segments which are selected by a switch on the front panel. The switch also selects HF and VHF antenna automatically.

The transverter is self-contained. It may be operated from 100/110/117/200/220 or 234 volt 50/60 Hz AC when the power transformer is appropriately wired. The FTV-250 is normally supplied for 117 volt AC and 12 volt DC operation.

The transverter weighs approximately 6 kg and is 210 m/m wide, 150 m/m high and 290 m/m deep.

SPECIFICATIONS

TRANSMITTER

Input Frequency	28 - 30 MHz
Input Voltage	3 Volts RMS
Input Impedance	Approximately 8 kilo ohms
PA Input	20 watts DC
Output Frequency	144 - 148 MHz
Output Impedance	50 ohm unbalanced
Spurious Radiation	Better than -60 dB

RECEIVER

Input Frequency	144 - 148 MHz
Antenna Impedance	50 ohm unbalanced
Sensitivity	SSB/CW: Better than S/N 20 dB at 0.5 u
	Volt antenna input signal
	AM: Better than S/N 10 dB at 1 u Volt
	antenna input signal
Internal Spurious	Better than 0 dB
Output Frequency	28 - 30 MHz
Output Impedance	50 ohms
Power Requirements	100/110/117/200/220/234 Volt 50/60 Hz AC
	or 13.5 Volt DC negative ground
Power Consumption	AC 0.75 VA
	DC 2.6 A at 10 watts antenna output
Size	210 (W), 150 (H), 290 (D) m/m
Weight	Approximately 6 kg

*The above values are in conjunction with ${\rm FT-101E}.$

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SEMICONDUCTORS

FET			
2SK19GR	3	2SK19Y	1
3SK40M	1	,1	1
SI TRANSISTOR			
2SC372Y	2	2SC373	1
2SC730	1	2SC735Y	1
2SC741	1	2SC784R	3
2SD313D	2	2N3055	1
2N5591	1	MRF208	1
CD DIONE			
GE DIODE			
1N60AM	2	1S188FM	1
SI DIODE			
1S1555	5	151941	3
10D-1	3	DS-130YD	1
M4B-5	1		10.40
ZENER DIODE			
1N4740			
WZ090		WZ061	1
W 2090	1	WZ110	1
VARACTOR DIODE			
1S1658	2	BB105GM	7
LED		tract of here in both in a second	

SL103

3

ACCESSORIES

AC Pow	er Cord	1	Coaxial Plug MP-7	1
Coax. C	Cable (A)	1	Fuse 2A	1
Coax. C	Cable (B)	1	DC Cord is optional.	
Coax. C	Cable (C)	1		

CONTROLS AND SWITCHES

FRONT PANEL



(1)	RF GAIN	The RF	GAIN	controls	the	gain	of	RF	amplifier	stage.
-----	---------	--------	------	----------	-----	------	----	----	-----------	--------

- (2) TUNE This control tunes the signal circuit for both transmitter and receiver for optimum performance.
- (3) BAND The BAND switch is a three position switch that selects the two meter amateur band. In the OFF position, the FTV-250 transverter is inoperative and the HF or six meter transverter, if used, will become operational. If the BAND switch of six meter transverter, when connected, is also in the OFF position, the HF antenna is automatically connected to the HF equipment.
- (4) METER This switch selects the meter mode to read exciter drive level and a relative power output.
- (5) HF 6M 2M The lamp shows the band in use.
- (6) METER The METER indicates the relative power output and drive level.



- 2M ANT Two meter antenna is connected here.
- (2) 2M 6M Refer to the interconnection diagram.
- (3) TRX (IN-OUT), 6M (TX-RX) RF input and output connectors. Refer to the interconnection diagram.
- (4) HF ANT HF antenna is connected here. If FTV-650B is also connected, the HF antenna is connected to the FTV-650B as illustrated in the interconnection diagram.
- (5) POWER Power receptacle. AC power cord is supplied with the transverter.
- (6) FUSE Fuse holder. For AC operation, a 1 amp fuse is used for 100/117 volt and 0.5 amp fuse on 200/234 volt operation.

INSTALLATION

The FTV-250 Transverter has been primarily designed for combination use with our FT-101/FT-201 transceivers and FL-101/FR-101 transmitter/receiver. The power supply is selfcontained.

The transverter should be placed in a location that has adequate space to permit free air circulation around the heat sink on the back panel.

The antenna and its location are the most important consideration. The antenna should always be as high and in the clear as possible, and a minimum distance of 10 feet should be maintained between the VHF and other antennas.

The most popular antenna types are either a quarter wave length whip with unity gain or a 5/8 wave length whip with a base matching device affording approximately 3.5 dB gain. A multi-element Yagi antenna is also widely used for DX communications.

To minimize loss in the antenna system, the use of the shortest length of the coaxial cable that is practical is recommended, avoiding any sharp angles or kinks. Use type RG-8U cable if the cable length exceeds 25 feet, while RG-58/U may be used for shorter lengths.

The transverter is designed for use in many areas of the world where the supply voltage may differ from the operator's local supply voltage. Therefore, before connecting the AC cord to the power outlet, be sure that the transformer windings agree with the local supply voltage. If not, please refer to Figure 1 for rewiring of the transformer primary connections.

CAUTION

PERMANENT DAMAGE WILL RESULT IF IMPROPER AC SUPPLY VOLTAGE IS APPLIED TO THE TRANSVERTER. OUR WARRANTY DOES NOT COVER DAMAGES CAUSED BY SUCH IMPROPER SUPPLY VOLTAGE.

Be sure proper fuse is used according to the local supply voltage; 1 amp for 100 - 117 volts and 0.5 amp for 200 - 234 volts.

For DC operation, use the DC power cord which may be available through your dealer.



Figure 1 Transformer Primary Wiring

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INTERCONNECTIONS







Figure 3 FTV-250, FTV-650B and TRANSCEIVER Combination



Figure 4 FTV-250 and FL/FR-101 Combination



Figure 5 FTV-250, FTV-650B and FL/FR-101 Combination

OPERATION

The tuning procedure of the transverter is not complicated, however, care should be exercised when tuning to insure peak performance of the two combined equipments, transverter and HF equipment.

The following paragraphs describe the procedures for receive and transmit tuning. It is assumed that the interconnection has been completed as shown on page 7 and 8.

INITIAL CHECK

Refer to the connection of the transverter to a power source, and carefully examine the unit for any visible damage. Check that the controls and switches are operating normally. Ensure that the power transformer winding (voltage specification marked on the rear panel) matches with the supply voltage. Ensure that the interconnection has been completed.

FREQUENCY SELECTION

The frequency is determined by the main tuning dial of the HF equipment in conjunction with the transverter BAND switch setting. The transverter BAND switch selects two bands, 144 through 146 MHz and 146 through 148 MHz. The HF equipment covers 2 MHz in four segments. The frequency relation between the transverter and the HF equipment is as follows;

TRANSVERTER	HF Equipment										
	10 A	10 B	10 C	10 D							
144 - 146 MHz	144.0-144.5	144.5-145.0	145.0-145.5	145.5-146.0							
146 - 148 MHz	146.0-146.5	146.5-147.0	147.0-147.5	147.5-148.0							

Table 1

RECEIVE

Set the BAND switches of both transverter and HF equipment for the desired band and tune to the signal by the main tuning dial of the HF equipment. Peak the TUNE control for maximum S-meter reading on the HF equipment. Adjust the RF GAIN of the transverter to reduce interferences from strong signals.

TRANSMIT

CAUTION:

A DUMMY LOAD OR ANTENNA SHOULD BE CONNECTED TO THE ANTENNA TERMINAL FOR TUNE UP OF THE TRANSVERTER OR THE HF EQUIPMENT.

Set the transverter BAND switch to OFF position. Prior to tuning the transverter, the HF equipment must be tuned to 10 meter band with a dummy load connected to the HF antenna terminal of the transverter. Tune up the HF equipment into the dummy load at the desired frequency given from Table 1.

After completion of the HF equipment tune up, set the MIC GAIN and CARRIER controls to fully counterclockwise position, O mark. Set the transverter BAND switch to the desired band and the METER switch to DRIVE position.

Set the HF equipment to TUNE position and set the HF equipment to the transmit mode by the PTT switch. Increase the CARRIER control until the transverter meter reading starts to increase. Peak the PRESELECTOR of the HF equipment and the DRIVE control of the transverter for maximum meter reading. Adjust the CARRIER control until the meter indication stays in the top of the green portion of the meter scale at maximum drive. Set the MODE switch to SSB mode. (Usually the USB mode is used in 2 meter band.)

Advance MIC GAIN until the meter indication goes up to the upper limit of the green portion on voice peaks when speaking normally into the microphone. On AM mode, the CARRIER LEVEL should be set to the 20% of PO indication on CW mode with the METER switch at PO position.

The MIC GAIN should be set at a level where the meter indication kicks up slightly, with voice peaks.

It is recommended to set the METER switch to the DRIVE position and observe the meter indication so as not to exceed the green portion during operation. Excessive drive may cause the distortion and splatter.

CIRCUIT DESCRIPTION

The following block diagram and circuit description will provide you with better understanding of the transverter.



FTV-250 BLOCK DIAGRAM

RECEIVER

The 144 MHz input signal from the antenna is fed through an antenna relay, RL1201 to pin 5 of the CONVERTER UNIT, PB-1517. The signal is amplified by the RF amplifier Q401, 3SK40M, dual gate MOS FET, and then fed to the gate of the mixer Q402, 2SK19Y, where the input signal is heterodyned with a local signal into 28 MHz IF signal.

The input and output circuits of the RF amplifier utilize a double tuned circuit, which is sharply tuned to the frequency of the received signal with the varactor diodes D401 through D404. Voltage to BB-105-GM is controlled by the TUNE control on the front panel, thus reducing cross and intermodulation.

The heterodyne crystal oscillator Q403, 2SC373, oscillates at 38.66 MHz for 144 - 146 MHz or 39.33 MHz for 146 - 148 MHz depending upon the BAND switch position. This signal is fed to the trippler Q404, 2SC784R, producing 116 or 118 MHz heterodyne signal. The heterodyne signal is fed through the buffer amplifier Q405, 2SC784R, to the receiver mixer 2SK19Y and the exciter mixer 2SK19Y. The converted 28 through 30 MHz IF signal is tuned by T401 and a varactor diode 1S1658 and then fed through the antenna change-over relay to the output terminal J5.

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TRANSMITTER

The 28 MHz signal from the RF output of the HF transmitter is fed through the antenna relay to pin 6 of ALC AMP UNIT, PB-1519. The 28 MHz signal is amplified by the ALC (Automatic Level Control) amplifier Q501, 2SK19GR, and fed to the EXCITER UNIT, PB-1516. The ALC voltage is fed through pin 7 to the gate circuit of Q501 and reduces the gain of Q501 to prevent distortion caused by over drive.

A part of the input signal is rectified by D501 and D502, 1S1555, and used to indicate the drive level on the meter.

The output from Q501 is fed to the balanced mixer, consisting of Q601 and Q602, 2SK19GR, where the signal is mixed with the heterodyne signal delivered to the center tap of the input transformer secondary, producing a 144 through 148 MHz signal.

The output signal from the balanced mixer passes through tuned circuits consisting of L601, L602 and L603 which are tuned by the varactor diodes D602, D603 and D604, BB-105-GM Voltages is varied by the TUNE control from the front panel. Thus the circuit is tuned exactly to the operating frequency, reducing spurious radiation.

The signal is amplified by the amplifier chain Q603, 2SC784R, Q604, 2SC741 and Q605, 2SC730, and fed to the BOOSTER UNIT, PB-1470. The output signal level from the Q605 is approximately 0.1 watt.

The signal from the EXCITER UNIT is fed to the BOOSTER UNIT and amplified by the driver amplifier Q1201, MRF208, and the final amplifier Q1202, 2N5591, which delivers 10 watts of RF power to the antenna through two stage lowpass filter and the antenna relay.

The bias voltage isstabilized at 9 volts by a zener diode D1209, 1N4740. Two diodes D1201 and D1202, 10D1, are used to protect the power transistors from damage due to heating. A small portion of the RF output is rectified by a diode D1203, 1S188FM, which delivers a resulting DC voltage to the meter where it provides an indication of the relative power output.

The DC voltage obtained from rectifying a small portion of the RF output by the ALC diode D1204, 1S-1555, which is biased by the ALC threshold control VR-1201, is applied to the gate of Q501 in the ALC AMP unit.



POWER SUPPLY

1

The power supply has been designed to operate from 100/110/117/200/220 or 234 volts AC 50/60 Hz or 12 volts DC negative ground.

Inserting the appropriate power plug into the rear panel receptacle makes the necessary connections to operate the supply in either AC or DC mode.

For AC operation, the DC voltage is supplied from the bridge connected rectifier unit D1501, M4B-5, which is connected to 17.5 volt secondary winding of the power transformer. The DC voltage is regulated at 13.5 volts by the voltage regulator circuit consisting of Q1501, 2SD313D, Q1, 2N3055 and Q1502, 2SC372Y.

The 13.5 volt voltage is further stabilized at 9 volts by the voltage regulator circuit consisting of Q1503, 2SC372Y, Q1504, 2SD313D and Q1505, 2SC372Y and supplied to the receiver circuit and the heterodyne oscillator circuit.

For DC operation, the positive voltage is connected to pin 3 and the negative voltage to pin 4 of the power receptacle. To protect the circuit from reverse connection of the DC voltage, D2, DS130YD, conducts heavily with reverse polarity connection to blow the line fuse in the DC cord.

CONTROL CIRCUITS

(1) FTV-250 and TRANSCEIVER Combination

When the BAND switch is in the OFF position, the supply voltage for the antenna relay RL-1 is disconnected, and as a result, DC or AC supply voltage for FTV-250 is disconnected. HF antenna is directly coupled through the relay contacts and J5 (TRX OUT) to the HF transceiver. 12.6 volts is supplied to heat up the final tubes of the HF transceiver, connecting pin 2 of J2 (2M) and J3 (6M) through the fourth wafer S1-4 of the BAND switch.

When the BAND switch is at 144 - 148 MHz positions (2 meter operation) the relay voltage is supplied through the switch and the relay activates for 2 meter operation, connecting the HF transceiver antenna jack, J5 to the 28 MHz IF output of the transverter through the contacts of the antenna relay RL-2. The antenna relay RL-2 is controlled by transmit-receive operation of the HF transceiver. The RL-2 supplies 9 volts for the receiver section on receiver mode and 13.5 volts for the transmitter section on transmit mode.

(2) FTV-250, FTV-650B and TRANSCEIVER Combination

In this combination, the HF antenna is connected to the 6 meter transverter and HF antenna terminal of the FTV-250 is connected to RCV jack of the FTV-650B as illustrated in the interconnection diagram. With the BAND switch at OFF position, the HF transceiver can be operated as described above and, in addition, 6 meter transverter can be operated as follows:

Signal from the HF antenna is fed to the HF transceiver through RCV jack of FTV-650B, J8 (HF ANT), RL-1 and J5 (TRX OUT). On transmit, on 6 meter band, 28 MHz signal from the HF transceiver is fed through J4 (TRX IN), RL-1 and J6 (6M TX) to the input terminal of the FTV-650B.

When the BAND switch of FTV-650B is OFF, the FTV-250 operates as described in the above paragraph.

MAINTENACE & ALIGNMENT

The FTV-250 transverter has been carefully aligned and tested at factory prior to shipment. With normal usage, it should not require other than the usual attention given to electronic equipment. Service or replacement of major parts may require subsequent realignment, but under no circumstances should realignment be attempted unless the operation of the transverter is fully understood, the malfunction has been analized and definitely traced to misalignment. Service work should only be performed by experienced personnel using proper test equipment.

TEST EQUIPMENT REQUIRED

(1) RF Signal Generator with 1 volt output at an output impedance of 50 ohms and a frequency coverage to 150 MHz.

(2) Vacuum Tube Volt-Ohm-Meter (VTVM). Hewlett-Packard Model 401B, or equivalent with an RF probe workable up to 150 MHz.

(3) Dummy Load, Yaesu YP-150, or equivalent with 50 ohm nonreactive load rated at 20 watt average power.

(4) Frequency Counter, YC-355D, or equivalent workable up to 200 MHz.

REGULATOR UNIT, PB-1469

The voltage adjustment should be done with AC power supply.

13.5 volts; Connect a VTVM DC probe between the 13.5 volt terminal (positive) and ground (negative). Adjust VR1501 for exact 13.5 volt reading on the VTVM.

9 volts: Connect a VTVM DC probe between the 9 volt terminal (positive) and ground (negative) and adjust VR1502 for exact 9 volt reading on the VTVM.



REG UNIT

VR UNIT, PB-1518

Set the TUNE control to 148 MHz setting. Connect the positive probe of VTVM to the center arm of forward potentiometer VR1a (TUNE control pot) located on front panel, and adjust VR104 for 5.5 volt reading on the VTVM. Set the TUNE control to 144 MHz setting and make sure that the voltage drops to 3 volts. Disconnect the VTVM positive probe and connect it to the center arm of rear potentiometer VR1b (TUNE control pot). Set the BAND switch to 146 -148 MHz segment and the TUNE control to



VR UNIT

148 MHz setting. Adjust VR101 for 4.3 volt on the VTVM. Set the TUNE control to 146 MHz and read the VTVM reading.

Set the BAND switch to 144 - 146 MHz segment and the TUNE control to 144 MHz. The VTVM reading should be same as the value measured at 146 MHz with the BAND switch setting of 146 - 148 MHz. Set the TUNE control to 146 MHz. The VTVM should read 4.3 volt.

If these values are not the same, adjust VR102 and VR103 alternately until the VTVM shows the same value at both high and low ends of both band segments.

CONVERTER UNIT, PB-1517

(1) Heterodyne Oscillator

Connect the VTVM RF probe to the base of Q404 and peak T402 for maximum VTVM reading, and set the T402 where the VTVM shows 80% of maximum reading. Connect the VTVM RF probe and frequency counter to the base of Q405 and peak T403 for maximum VTVM reading. Connect the VTVM RF probe to pin 8 and peak T403 for maximum VTVM reading. The coils should be adjusted until the VTVM reading shows the same value with the BAND switch setting of 144 - 146 MHz and 146 - 148 MHz. The output frequency should be 116 MHz for 144 - 146 MHz and 118 MHz for 146 - 148 MHz band.



CONVERTER UNIT

(2) Receiver Front End

Prior to this alignment, the VR unit should be realigned as described in the preceding paragraph. Connect the output of the signal generator set at 146 MHz to the antenna connector.

Set the controls and switch as follows.

146 MHz TUNE

Fully clockwise position RF GAIN

Peak TC401, TC402, TC403, TC404 and T401 for maximum S-meter reading. After above procedures, make sure that the TUNE control indication matches to the frequency on the front panel when the receiver is tuned to 144 MHz and 146 MHz respectively.

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Set the BAND switch to 146 - 148 MHz segment, and make sure that the TUNE control indicates 146 MHz, 147 MHz and 148 MHz when the receiver is tuned to these frequency respectively.

ALC AMP UNIT, PB-1519

Set the METER switch of FTV-250 to DRIVE position and the controls of the HF transceiver as follows.

BAND	10B
FREQUENCY	29 MHz
MODE	TUNE
CARRIER	0

Tune up the HF transceiver at 29 MHz and connect the VTVM RF probe to pin 6 of PB-1519. Increase the CARRIER control until the VTVM indicates 3 volt RMS. Connect the VTVM RF probe to pin 3 and peak TC501 for maximum VTVM reading.

Adjust VR501 until the meter shows 0.3 in the green scale.

EXCITER UNIT, PB-1516

Set the HF transceiver to the same condition as ALC AMP alignment. Set the TUNE control to 145 MHz and the BAND to 144 - 146 MHz. Connect the RF probe of VTVM to the RF input terminal of the BOOSTER UNIT. Peak TC601 through TC607 and T601 for maximum VTVM reading. Connect the VTVM RF probe to the hot end of L602 (junction point between L602 and C614). Adjust VR601 for minimum VTVM reading.

TC601 through TC607 should be realigned for maximum power output at 146 MHz after the completion of the BOOSTER UNIT realignment.



ALC AMP UNIT



EXCITER UNIT

BOOSTER UNIT, PB-1470

Set the controls and switches as follows:

HF Transceiver

BAND	10 D
FREQUENCY	30 MHz
MODE	TUNE
CARRIER	At the level which gives 3 volt (RMS) RF input at FTV-250 RF input.



FTV-250

BAND	144 - 146 MHz
TUNE	146 MHz (12 o'clock position)

It is assumed that the FTV-250 alignment is completed, except the BOOSTER UNIT. Set the VR1201 and VR1202 to fully counterclockwise position. Connect the RF probe of VTVM to the base of Q1201 and peak TC1201, and TC605 and TC607 in the EXCITER UNIT for maximum VTVM reading.

Connect the RF probe of VTVM to the base of Q1202 and peak TC1202 for maximum VTVM reading.

Set the METER switch of the FTV-250 to PO position and peak TC1201, TC1202, TC1203 and TC1204 for maximum meter indication. Adjust VR1201 until the power meter (dummy) shows exactly 10 watts.

Set the METER switch to PO position and adjust VR1202 until the meter indicates 0.8 at 10 watts output.

CONNECTOR RESISTANCE CHART

UNIT	PIN	1	2	3	4	5	6	7	8	9	10	11	12	13	14
	J1	00	~~~	œ	Е	-	-	-	-	-	-		-	-	-
MAIN CHASSIS	J2	550K	00	8	∞	00	00	00	E	4.6K	~~~~	~	-	-	-
	\mathbf{J}_3	600K	00	~~~~	~~~~	00		00	Е	10K	00	130K	-	-	-
REG		82	95	95	50	28	10	10	9 <u>77</u> 9	-	-	-	-	-	-
CONVER- TER		500K	500K	82	Е	0	E	82	0	82	Е	0	Е	** 3K	** 18K
ALC AMP		Е	Е	00	₩ 1.2K	Е	22K	180K	13	-	-	_	-	-	-
EXCITER		00	Ė	0	₩ 3K	** 18K	13	-	-	-	-	-	-	-	-
BOOSTER	Jə	E	0	₩ 3K	₩ 1.7K	82	13	13	-	-	-	-	-		-

POWER ······OFF BAND ······OFF RF GAIN ······MAX METER SWITCH·····PO

N

4

Measured with 20 k ohm/V. Values are in OHM.

VOLTAGE CHART

UNIT	-21.4	E	(S)	С	(D)	В	(G)			E(S)		C (D)		B (G)	
	-	R	Т	R	Т	R	Т	UNIT		R	Т	R	Т	R	Т
MAIN CHASSIS	Qı	13.5	13.5	18.0	18.0	14.0	14.0	ALC AMP	Q501	0	0.95	0	13.0	0	0
REG	Q1501	14.0	14.0	18.0	18.0	14.6	14.6		Q601	0	1.75	0	12.5	0	0
	Q1502	9.0	9.0	14.6	14.6	9.6	9.6	EXCI- TER	Q502	0	1.75	0	12.5	0	0
	Q1503	9.6	9.6	13.5	13.5	10.2	10.2		Q603	0	1.25	0	13.0	0	1.9
	Q1504	9.0	9.0	13.5	13.5	10.2	10.2		Q604	0	0.75	0	13.0	0	1.65
	Q1505	6.0	6.0	10.2	10.2	6.4	6.4		Q605	0	0	0	13.0	0	0.6
	Q401	2.9	0	9.0	0	G1 0.8 G2 4.4	0.	BOOS- TER	Q1201	0	0	0	13.0	0	0.7
	Q402	1.7	0	9.0	0	0	0.		Q1202	0	0	0	13.0	0	0.7
CONVER- TER	Q403	1.5	1.5	8.3	8.3	1.54	1.54								
	Q494	0.85	0.85	8.5	8.5	0.24	0.24								
	Q405	0.8	0.8	8.5	8.5	1.2	1.2								

Measured with VTVM. Values are in VOLT DC.

FTV-250 PARTS LIST

2 TRANSISTOR	Q FET &	TRANSIS	TOR	
2N3055	401	FET	3SK40M	
	402	FET	2SK19Y	
DIODE		Tr	2SC373	
, 6 Si 1S1555	404, 405	Tr	2SC784R	
, 4, 5 1S1941				
DS-130YD		a series and		
	D DIODE			
+		Ge		
RESISTOR		Varactor		
CARBON COMPOSITION	$401 \sim 404$	Varactor	BB105GM	1
$\frac{1}{2}W$ 1KQ				
$\frac{1}{2}$ W 470KQ	X CRYST			
$1/2$ $1/2$ 1 $M\Omega$	401	HC25/U		38. 6666MHz
WIRE WOUND	402	HC25/U		39. 3333MH2
$2W = 150\Omega$	-	0.0		
	R RESIST		THE N.C.	
		CARBON		1000
/R POTENTIOMETER	415, 418, 422, 4	126		100Ω 2200
EVL-BOAS 15B53 5KB	425, 429		¼W ¼W	220S 270S
EWF-POAS 15098 5KB/50KB	408, 421		% W % W	270s. 1. 5Ks
	413, 430		1/4 W	2. 2KS
C CAPACITOR	409, 417, 424			
CERAMIC DISC	420		¼W ¼W	3. 3KG 4. 7KG
$3, 6, 7$ 50WV $0.01 \mu F$	428		% W % W	4.7KS 10KS
$2, 4, 9 \sim 11$ 50WV $0, 047 \mu F$	416, 419		24 W 24 W	22KS
$1.5 \text{KV} = 0.0047 \mu \text{F}$	427		1/4 W	33KG
	404		³⁴ W ¹ / ₄ W	and if dot will be reaching
MYLAR	423		<u>%</u> W %W	47KS 68KS
$50WV = 0.1 \mu F$	405, 406			100KS
	403, 407, 412		W VW	
ELECTROLYTIC	401, 402, 410,	111, 414	1/4 W	1 M S
25WV 220µF				
	C CAPAC	TOR		
T DOWED TRANSFORMER		CERAMI	DISC	
PT POWER TRANSFORMER	437, 438	CERAMIN	50WV	3PF(CH)
52-45	401, 402, 411, 4	113	50WV	5PF(CH)
A NACTOR	401, 402, 411, 427, 432	*10	50WV	12PF(CH)
M METER 47820C1	427, 432		50WV	15PF(CH)
4782001	403, 414, 421		50WV	20PF(CH)
RL RELAY	403, 414, 421		50WV	24PF(CH)
	417		50WV	150PF(CH)
AP3241	417, 420, 425		50WV	0.001µI
RLS RELAY SOCKET	413, 420, 423 $404, 406 \sim 410,$		50WV	0.01µI
AP3844	418, 419, 422,			
A1 5044	430, 431, 436	121, 120, 18	•	
S SWITCH	405, 433~435		50WV	0.047µI
RS32-1-4-3	100, 100 400			
2 ESR-E132R15A		1		
AH-71507	TC TRIMM	ER CAPA	CITOR	
	401 - 404	ECV-1ZW		10PI
J CONNECTOR	101 101			
QMS-AB4M	L INDUCT	OR		
2 SA-602B	401	and the second	A #221003	
PA-603B	402		B #221004	
I~7 CN-7017	403	and the second sec	A #221005	
JSO-239	404	the second is in the second	B #221006	
) S9-241Y	405		10 µ H	
10 ML-3161	403	RFC	250 µ H	
ATTAC VAVA	406, 407	RFC	1mH	
H FUSE HOLDER				
I SN-1001				
	T TRANS	FORMER	and the set	
	401		R12-4423	
	402		R12-4425	
	and the second s			
CONVERTER UNIT	403, 404		R12-4862	
CONVERTER UNIT	403, 404		R12-4862	

ALC AMP UNIT			C CAPACITOR DIPPED MICA			
PB PRINTED CIRCUIT BOARD			DIPPED MICA 604, 605 50WV 390PH			
1519 (A~Z)	JOIT DOAN		004,005		00111	0.001 1
			-			
Q FET				CERAM	HC DISC	
501	2SK19GF	2	615			0.5PF
			614, 616			5PF (CH)
D DIODE			611, 612, 62:	2,626	50WV	10PF (CH
D DIODE 501, 502 Si	1S1555		618 601, 606, 60	7 600 604	50WV 50WV	
501, 502 51	151555		628, 629	1, 023, 024	50WV	$0.001 \mu F$
			602,608~6	10 613		0.01µF
R RESISTOR	12		617.619~6		00111	0.0141
	N FILM	1011	627,630			
503, 507	1⁄4 W	100Ω		515 - 10 - 10 - 10 - 10 - 10 - 10 - 10 -		1000
505	1⁄4 W	220Ω	and the second s			ST 3017 - 510
501	1/4 W	$10 \text{K}\Omega$	TC TRIM			
502	1/4 W	22KΩ	601~603,60			
504	14W	100KΩ	604, 606, 603	7 ECV-1Z	W 20×50	20PI
VR POTENTIOMET	ER	12-12-12-12-12-12-12-12-12-12-12-12-12-1	L INDU	CTOR		
501 EVL-S3		10KB	601		# 22100	7
			602		# 22100	
C CAPACITOR			603		# 22100	
CERAN			604, 606		# 22101	
501		10PF (CH)	605, 607, 609)	# 22101	
506, 507 504, 508	50WV	82PF(CH)	608	- DDA	#22004	
504, 508 502, 503, 505	50WV 50WV	100PF (CH) 0.01µF	$610 \sim 612$	RFC		10μ H
502, 503, 505	50WV	$0.01 \mu F$ 0.047 μF	T TRAN	SEORMER	>	
	00111	0.041/21	601	and the second	R12-4423	
TC TRIMMER CAP	ACITOR				1000000	
	W 40×32	40PF				
501 ECV-1Z	W 40×32	40PF				
501 ECV-1Z L INDUCTOR		40PF	BOOS	TER UNI	г	
501 ECV-1Z		40PF				30
501 ECV-1Z	\$220044	40PF	BOOS PB PRIN 1470 (A ~ Z)	TED CIRC		RD
501 ECV-1Z L INDUCTOR 501 RFC EXCITER UNIT	#220044		PB PRIN 1470 (A ~ Z)	ED CIRC		RD
501 ECV-1Z L INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC	#220044		PB PRIN 1470 (A~Z) Q TRAN	SISTOR	UIT BOAI	RD
501 ECV-1Z L INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC	#220044		PB PRINT 1470 (A~Z) Q TRAN 1201	SISTOR MRF-20	UIT BOAI	RD
501 ECV-1Z L INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z)	#220044		PB PRIN 1470 (A~Z) Q TRAN	SISTOR	UIT BOAI	RD
501 ECV-1Z L INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) Q FET & TRANS	#220044 UIT BOAR	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202	FED CIRC SISTOR MRF-203 2N5591	UIT BOAI	RD
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) 2 PET & TRANS 501, 602 FET	#220044 UIT BOAR ISTOR 2SK19GR	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI	SISTOR MRF-203 2N5591	UIT BOAI	
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) 2 Q FET & TRANS 501, 602 FET 505 Tr	# 220044	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203	FED CIRC SISTOR MRF-203 2N5591 E Ge	UIT BOAF 8 1S188FN	
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) 2 Q FET & TRANS 501, 602 FET 505 Tr 504 Tr	#220044 UIT BOAR ISTOR 2SK19GR	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204	FED CIRC SISTOR MRF-203 2N5591 E Ge Si	UIT BOAF 8 1S188FN 1S1555	
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) 2 FET & TRANS 501, 602 FET 505 Tr 504 Tr 503 Tr	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203	FED CIRC SISTOR MRF-203 2N5591 E Ge	UIT BOAF 8 1S188FN	
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) 2 FET & TRANS 501, 602 FET 505 Tr 504 Tr 503 Tr 503 Tr 503 Tr	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1201, 1202 1209	FED CIRC SISTOR MRF-200 2N5591 E Ge Si Si Zener	UIT BOAF 8 1S188FN 1S1555 10D-1	
501 ECV-1ZLINDUCTOR 501 RFCEXCITERUNITPBPRINTEDCIRCCIRC $1516 (A \sim Z)$ QFET $501, 602$ FET 505 Tr 504 Tr 503 Tr 503 Tr 505 Si	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1201, 1202	SISTOR MRF-200 2N5591 E Ge Si Si Zener	UIT BOAF 8 1S188FN 1S1555 10D-1 1N4740	A
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) 2 FET & TRANS 201, 602 FET 501, 602 FET 501, 602 FET 505 Tr 504 Tr 504 Tr 503 Tr 503 Tr 504 Tr 503 Tr 505 Si 501 Varacto	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1201, 1202 1209 R RESIS	SISTOR MRF-200 2N5591 E Ge Si Si Zener	UIT BOAF 8 1S188FN 1S1555 10D-1 1N4740 N COMPC	A
501 ECV-1Z INDUCTOR 501 S01 RFC EXCITER UNIT PB PRINTED CIRC IS16 (A~Z) 2 FET & TRANS S01, 602 FET 505 Tr S01, 602 FET 505 Tr S04 Tr 503 Tr D DIODE 505 Si S01 Varacto Varacto	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1201, 1202 1209 R 1204 1209	SISTOR MRF-200 2N5591 E Ge Si Si Zener	UIT BOAF 8 1S188FN 1S1555 10D-1 1N4740 N COMPC ½W	Δ DSITION 10Ω
501 ECV-1Z INDUCTOR 501 S01 RFC EXCITER UNIT PB PRINTED CIRC IS16 (A~Z) 2 FET & TRANS S01, 602 FET 505 Tr S01, 602 FET 505 Tr S04 Tr 503 Tr D DIODE 505 Si S01 Varacto Varacto	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1209 R 1204 1209	SISTOR MRF-200 2N5591 E Ge Si Si Zener	UIT BOAF 8 1S188FN 1S1555 10D-1 1N4740 N COMPC ½W ½W	Δ DSITION 10Ω 22Ω
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC IS16 (A~Z) 2 FET & TRANS S01, 602 FET 505 Tr S01, 602 FET 505 Tr S04 Tr 503 Tr D DIODE 505 Si 501 Varacto 502~604 Varacto	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1209 R RESIS 1204 1209	SISTOR MRF-200 2N5591 E Ge Si Si Zener	UIT BOAF 8 1S188FN 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W	Δ DSITION 10Ω 22Ω 56Ω
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC IS16 (A~Z) 2 FET 801, 602 FET S01, 602 FET 505 Tr 503 Tr S01 FET S04 Tr 503 Tr D DIODE 505 Si 501 Varacto S02~604 Varacto SI 502~604 Varacto R RESISTOR R SI 501 SI	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1209 R RESIS 1204 1209 1204 1203 1204 1209	SISTOR MRF-200 2N5591 E Ge Si Si Zener	UIT BOAF 8 1S188FN 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W	Δ DSITION 10Ω 22Ω 56Ω 120Ω
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC IS16 (A~Z) 2 FET S01, 602 FET 505 S01, 602 FET 503 S01, 602 FET 504 S03 Tr 503 DIODE 505 Si S01 Varacto 502~604 Varacto RESISTOR CARBOI	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1209 R 1204 1209 1204 1203 1204 1209	SISTOR MRF-200 2N5591 E Ge Si Si Zener	UIT BOAF 8 1S188FN 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W ½W	Δ DSITION 10Ω 22Ω 56Ω 120Ω 330Ω
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) 2 FET 8 201, 602 FET 505 Tr 503 Tr 503 Tr 504 Tr 503 Tr 505 Si 501 Varacto 505 Si 501 Varacto 505 Si 501 Varacto 502~604 Varacto 502~604 CARBOI 601 621 621 638	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W	D	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1209 R R RESIS 1204 1201 1203 1204 1201 1203 1203 1205 1202 1202	SISTOR MRF-200 2N5591 E Ge Si Si Zener	UIT BOAF 8 1S188FN 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W	Δ DSITION 10Ω 22Ω 56Ω 120Ω 330Ω
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) 2 FET 8 20 FET & TRANS 501, 602 FET 501 602 FET 505 Tr 503 Tr 503 Tr 504 Tr 503 Tr 505 Si 501 Varacto 505 Si 501 Varacto 505 Si 501 Varacto 502 604 Varacto 502 601 Varacto CARBOI 519, 621 518 508, 614 508, 614 508	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W	D D 1 220 560 1000	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1209 R RESIS 1204 1201 1203 1204 1201 1203 1205 1202 1206	SISTOR MRF-200 2N5591 E Ge Si Si Zener	UIT BOAF 8 1S188FN 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W ½W	Δ DSITION 10Ω 22Ω 56Ω 120Ω 330Ω
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 516 (A~Z) 2 FET & TRANS 501, 602 FET	# 220044 UIT BOAR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W ¼W	D 22Ω 56Ω 100Ω 220Ω	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1209 R R RESIS 1204 1201 1203 1204 1201 1203 1205 1202 1206 VR	SISTOR MRF-203 2N5591 Ge Si Zener TOR CARBOI	UIT BOAF 8 1S188FM 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W	Δ DSITION 10Ω 22Ω 56Ω 120Ω 330Ω 15KΩ
ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) D FET Strange 2 FET TRANS Strange 301, 602 FET Strange Strange 303 Tr Strange Strange 304 Tr Strange Strange 303 Tr Strange Strange 304 Tr Strange Strange 305 Strange Strange Strange 301 Varacto Varacto Strange 302~604 Varacto Strange Strange 303 CARBO Strange Strange 304 Strange Strange Strange 305 Strange Strange Strange 302~604 Varacto Strange Strange 303 Strange Strange Strange 304 <	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W ¼W ¼W	D 220 560 1000 2200 3300	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1209 R R RESIS 1204 1201 1203 1204 1201 1203 1205 1202 1206 VR VR POTE 1202 2	SISTOR MRF-203 2N5591 Ge Si Zener TOR CARBOI	UIT BOAF 8 1S188FM 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W ½W ½W ½W ½W ½W	A DSITION 10Ω 22Ω 56Ω 120Ω 330Ω 15KΩ 5KB
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) 2 FET 8 20 FET & TRANS 501, 602 FET 501, 602 FET 505 Tr 503 Tr 503 Tr 503 Tr 503 501 Varacto 505 Si 501 Varacto 502~604 Varacto 501 Varacto CARBOI 519, 621 518 508, 614 513 508, 614 513 516 517 517 518 518 518 518 518 516 517 518 518 518 518 516 517 518 518 518 518 518 518 518 516 517 518 518 518 518 518 518 518 518 518 516 517 518 516	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W ¼W ¼W ¼W	D 220 560 1000 2200 3300 2.7KΩ	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1209 R R RESIS 1204 1201 1203 1204 1201 1203 1205 1202 1206 VR	SISTOR MRF-203 2N5591 Ge Si Zener TOR CARBOI	UIT BOAF 8 1S188FM 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W	A DSITION 10Ω 22Ω 56Ω 120Ω 330Ω 15KΩ 5KB
ECV-1Z INDUCTOR $EXCITER$ UNIT EXCITER UNIT PB PRINTED CIRC $EXCITER$ UNIT PB PRINTED CIRC $EXCITER$ UNIT PB PRINTED CIRC $EXCITER$ UNIT PB PRINTED CIRC $EXCITER$ UNIT PB PRINTED CIRC $EXCITER$ UNIT PB PRINTED CIRC $EXCITER$ TRANS Solid Caracto $EXCITER$ Varacto Solid Varacto $EXCITER$ CARBOI Solid Caracto $EXCITER$ CARBOI Solid Caracto $EXCITER$ CARBOI Solid Solid Solid $EXCITER$ CARBOI Solid Solid Solid Solid Solid $EXCITER$ Solid Solid Solid Solid Solid Solid Solid $EXCITER$	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W ¼W ¼W ¼W ¼W ¼W	D 22Ω 56Ω 100Ω 220Ω 330Ω 2.7KΩ 3.3KΩ	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1209 R RESIS 1204 1203 1204 1203 1204 1203 1205 1202 1206 VR VR <pote< td=""> 1201</pote<>	FED CIRC SISTOR MRF-203 2N5591 E Ge Si Zener TOR CARBOI CARBOI EVL-SO. EVL-SO.	UIT BOAF 8 1S188FM 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W ½W ½W ½W ½W ½W	A DSITION 10Ω 22Ω 56Ω 120Ω 330Ω 15KΩ 5KB
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 ($A \sim Z$) 0 FET 8 20 FET & TRANS 501, 602 FET 505 Tr 503 Tr 503 Tr 503 Tr 505 Si 501 Varacto 505 Si 501 Varacto 505 Si 501 Varacto 505 Si 501 Varacto 502~604 Varacto 519, 621 518 508, 614 513 516 517 512 522 522 533 533	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W	D 22Ω 56Ω 100Ω 220Ω 330Ω 2.7KΩ 3.3KΩ 4.7KΩ	PB PRINT 1470 (A ~ Z) Q TRAN 1201 1202 D DIODI 1203 1204 1209 R R RESIS 1204 1201 1203 1204 1201 1203 1205 1202 1206 VR VR POTE 1202 2	SISTOR MRF-203 2N5591 Ge Si Zener TOR CARBOI CARBOI EVL-SO EVL-SO	UIT BOAF 8 1S188FM 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W ½W ½W ½W % % % % % %	A DSITION 10Ω 22Ω 56Ω 120Ω 330Ω 15KΩ 5KB
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) 2 FET 8 20 FET & TRANS 501, 602 FET 501, 602 FET 505 Tr 504 Tr 503 Tr 503 Tr 503 501 Varacto 505 Si 501 Varacto 502~604 Varacto 501 CARBO 519, 621 518 508, 614 513 516 519, 621 518 508, 614 513 516 517 512 22 511 512 513 516	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W	D 22Ω 56Ω 100Ω 220Ω 330Ω 2.7KΩ 3.3KΩ 4.7KΩ	PB PRINT 1470 (A~Z) Q TRAN 1201 1202 D DIODI 1203 1204 1209 R RESIS 1204 1201 1203 1204 1201 1203 1204 1205 1202 1206 VR VR POTE 1202 1201	FED CIRC SISTOR MRF-203 2N5591 E Ge Si Zener TOR CARBOI CARBOI EVL-SO. EVL-SO.	UIT BOAF 8 1S188FM 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W ½W ½W ½W ½W ½W % % % %	Δ DSITION 10Ω 22Ω 56Ω 120Ω 330Ω 15KΩ 5KB 10KB
$ECV-1Z$ INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A $\sim Z$) C FET & TRANS 501, 602 FET & Tr & Tr 503 Tr & Tr & Tr 504 Tr & 003 Tr 505 Si & 001 Varacto 505 Si & 002~604 Varacto 505 Si & 001 Varacto 519, 621 & 018 & 008, 614 & 013 516 & 017 & 012 & 012 522 & 011 & 014, 605 & 014	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W	D 22Ω 56Ω 100Ω 220Ω 330Ω 2.7KΩ 3.3KΩ 4.7KΩ 15KΩ 56KΩ	PB PRINT 1470 (A~Z) Q TRAN 1201 1202 D DIODI 1203 1204 1201, 1202 1209 R RESIS 1204 1203 1204 1201 1203 1204 1205 1202 1206 VR VR POTE 1201 C CAPA0 1216	SISTOR MRF-203 2N5591 Ge Si Zener TOR CARBOI CARBOI EVL-SO EVL-SO	UIT BOAF 8 1S188FM 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W ½W ½W ½W ½W	Δ DSITION 10Ω 22Ω 56Ω 120Ω 330Ω 15KΩ 5KB 10KB 2PF (CH)
$ECV-1Z$ INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A $\sim Z$) C FET & TRANS 501, 602 FET & Tr & Tr 503 Tr & Tr & Tr 504 Tr & 003 Tr 505 Si & 001 Varacto 505 Si & 002~604 Varacto 505 Si & 001 Varacto 519, 621 & 018 & 008, 614 & 013 516 & 017 & 012 & 012 522 & 011 & 014, 605 & 014	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W	D 22Ω 56Ω 100Ω 220Ω 330Ω 2.7KΩ 3.3KΩ 4.7KΩ	PB PRINT 1470 (A~Z) Q TRAN 1201 1202 D DIODI 1203 1204 1201, 1202 1209 R RESIS 1204 1201 1203 1205 1202 1206 VR POTE 1202 1201 C CAPA0 1216 1217, 1223	SISTOR MRF-203 2N5591 Ge Si Zener TOR CARBOI CARBOI EVL-SO EVL-SO	UIT BOAF 8 1S188FM 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W ½W ½W ½W ½W	А DSITION 10Ω 22Ω 56Ω 120Ω 330Ω 15КΩ 5КВ 10КВ 2PF (CH) 5PF (CH)
$ECV-1Z$ INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A $\sim Z$) C FET & TRANS 501, 602 FET & Tr & Tr 503 Tr & Tr & Tr 504 Tr & 003 Tr 505 Si & 001 Varacto 505 Si & 002~604 Varacto 505 Si & 001 Varacto 519, 621 & 018 & 008, 614 & 013 516 & 017 & 012 & 012 522 & 011 & 014, 605 & 014	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W	D 22Ω 56Ω 100Ω 220Ω 330Ω 2.7KΩ 3.3KΩ 4.7KΩ 15KΩ 56KΩ	PB PRINT 1470 (A~Z) Q TRAN 1201 1202 D DIODI 1203 1204 1201, 1202 1209 R RESIS 1204 1203 1204 1201 1203 1204 1201 1202 1202 1206 VR POTE 1202 1201 C C 1216 1217, 1223 1201, 1205	SISTOR MRF-203 2N5591 Ge Si Zener TOR CARBOI CARBOI EVL-SO EVL-SO	UIT BOAF 8 1S188FM 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W ½W ½W ½W ½W	А DSITION 10Ω 22Ω 56Ω 120Ω 330Ω 15КΩ 10КВ 10КВ 2PF (CH) 5PF (CH) 10PF (CH)
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) 2 FET 20 FET & TRANS 501, 602 FET 505 503 Tr 503 504 Tr 503 505 Si 501 505 Si 501 505 Si 501 505 Si 502 505 Si 501 505 Si 501 505 Si 502 501 Varacto 502 604 Varacto 519, 621 518 508, 614 513 516 502 603, 606, 607, 609, 6 502 603, 606, 607, 609, 6	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W	D 22Ω 56Ω 100Ω 220Ω 330Ω 2.7KΩ 3.3KΩ 4.7KΩ 15KΩ 56KΩ	PB PRINT 1470 (A~Z) Q TRAN 1201 1202 D DIODI 1203 1204 1201, 1202 1209 R RESIS 1204 1201 1203 1204 1201 1203 1204 1201 1202 1202 1202 1202 1203 1204 1205 1202 1201 C C 1216 1217, 1223 1201, 1205 1213~1215	SISTOR MRF-203 2N5591 Ge Si Zener TOR CARBOI CARBOI EVL-SO EVL-SO	UIT BOAF 8 1S188FM 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W ½W ½W ½W ½W	А DSITION 10Ω 22Ω 56Ω 120Ω 330Ω 15КΩ 10КВ 10КВ 2PF (CH) 5PF (CH) 10PF (CH) 20PF (CH)
501 ECV-1Z INDUCTOR 501 RFC EXCITER UNIT PB PRINTED CIRC 1516 (A~Z) 0 FET 8 20 FET & TRANS 801, 602 FET 305 Tr 503 Tr 304 Tr 503 Tr 305 Si 501 Varacto 302~604 Varacto 502~604 Varacto 308, 614 513 516 517 519, 621 518 508, 614 513 516 502 603, 606, 607, 609, 6 602, 603, 606, 607, 609, 6	# 220044 UIT BOAR ISTOR 2SK19GR 2SC730 2SC741 2SC784R 10D-1 r 1S1658 r BB105GM N FILM ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W ¼W	D 22Ω 56Ω 100Ω 220Ω 330Ω 2.7KΩ 3.3KΩ 4.7KΩ 15KΩ 56KΩ	PB PRINT 1470 (A~Z) Q TRAN 1201 1202 D DIODI 1203 1204 1201, 1202 1209 R RESIS 1204 1203 1204 1201 1203 1204 1201 1202 1202 1206 VR POTE 1202 1201 C C 1216 1217, 1223 1201, 1205	SISTOR MRF-203 2N5591 Ge Si Zener TOR CARBOI CARBOI EVL-SO EVL-SO	UIT BOAF 8 1S188FM 1S1555 10D-1 1N4740 N COMPC ½W ½W ½W ½W ½W ½W ½W ½W ½W ½W	А DSITION 10Ω 22Ω 56Ω 120Ω 330Ω 15КΩ 10КВ 10КВ 2PF (CH) 5PF (CH) 10PF (CH)

1202, 1204, 1208, 1210 50WV	$0.001\mu\mathrm{F}$	1503	Zener WZ110	
1218~1220 50WV 1222 50WV	$0.01 \mu F$ 0.047 μF		CHICK HISCHICS	
1222 00111	0.011/-1			
		R RESIS		
ELECTROLYTIC	10.5	1509	CARBON FILM	2200
1203, 1207, 1209 16WV	10µF	1511		2702
TC TRIMMER CAPACITOR		1501		330Ω
1202~1204 P-100DS 20P	20PF	1510, 1512		470Ω
$\frac{1202}{1201} \frac{140000}{\text{ECV-1ZW}} \frac{50}{50} \times 40$	50PF	1505	1/4 W	560Ω
		1502	¼ W	680Ω
A CONTRACTOR OF A CONTRACT OF A CONTRACT		1503	1/4 W	820 Ω
INDUCTOR		1508	1⁄4 W	1KΩ
1201, 1207 # 221019		1504	1⁄4 W	2. 7KΩ
1202, 1203 # 221022				
$1204 \sim 1206, 1208, 1209 $ # 221020		VD DOTE	ITIOMETER	
1211, 1212 RFC #221021	00 11		NTIOMETER SR19R	470B
1210 RFC	$22\mu\mathrm{H}$	1501, 1502	SKIAK	47015
		C CAPA	CITOR	
RL RELAY			CERAMIC DISC	
1201 LZ-2G		1507	50WV	$0.01 \mu F$
CONNECTOR			MYLAR	
CONNECTOR 11201 JSO-239		1504	50WV	0.001µF
P1201 SI-8501	water and			
			ELECTROLYTIC	
VR UNIT		1503	25WV	100 µ F
		1508	- 16WV	220 µ F
PB PRINTED CIRCUIT BOARD		1505 1501, 1502	16WV 25WV	470 µF 2200 µF
1518 (A~Z)		1501, 1502	20 W V	2200,41
R RESISTOR			ACCESSION OF THE OWNER OF	
CARBON FILM				
101 /4W	$2.7 K\Omega$			
O DOTENTIONICTED				1
VR POTENTIOMETER 104 EVL-S3AA0014	10KB			
102, 103 EVL-S3AA0014 102, 103 EVL-S3AA0054	50KB			The section of the section
101 EVL-S3AA0015	100KB			
In Br				
LED UNIT PB PRINTED CIRCUIT BOARD 1520 (A~Z)				
D LIGHT EMITTING DIODE				
201~203 SL-103				
R RESISTOR CARBON FILM				
203 KRBON FILM	5600		The state of the s	
201, 202 ¼W	1KΩ			
· · · · · · · · · · · · · · · · · · ·				
REG UNIT				
PB PRINTED CIRCUIT BOARD				
1469 (A~Z)				
			1	
1502, 1505 2SC372Y				
1502, 1505 2SC3724 1503 2SC735Y		C. C	A STATE OF STATE OF STATE	
1501, 1504 2SD313D				
D DIODE				
1501 Si M4B-5				
1505 Zener WZ061 1502 Zener WZ090				









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